

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteri	stic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	$V_{\sf CEO}$	45	V
	BC848		30	
Emitter Base Voltage	BC846, BC847	\/	6.0	V
Emitter-Base Voltage	BC848	V _{EBO}	5.0	v
Continuous Collector Current		Ic	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	_	310	mW	
	(Note 7)	P _D	350		
Thermal Decistance, Junction to Ambient	(Note 6)	0	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357		
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-65 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

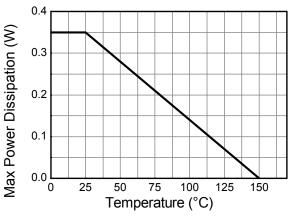
^{7.} Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

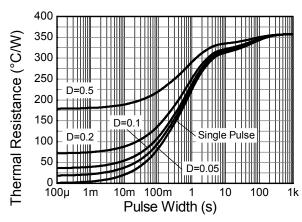
^{8.} Thermal resistance from junction to solder-point (at the end of the leads).

^{9.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



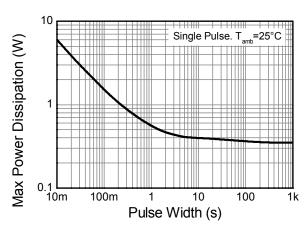
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

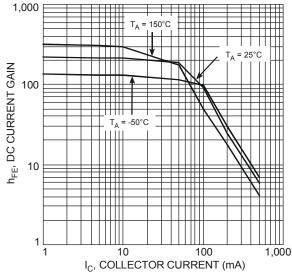
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition		
BC846			80						
Collector-Base Breakdown V	oltage	BC847	BV_CBO	50	_	_	V	$I_C = 10\mu A$	
		BC848		30				,	
Collector-Emitter Breakdown	Voltago	BC846		65					
(Note 10)	voltage	BC847	BV_CEO	45	_	_	V	$I_C = 10mA$	
(14010-10)		BC848		30					
Emitter-Base Breakdown Vol	tane	BC846 / BC847	BV _{EBO}	BV _{FBO} 6	_	_	V	I _E = 1μA	
Emilier Base Breakdown voi	tage	BC848	DVEBO	5				,	
Collector Cutoff Current			I _{CBO}	_	_	15	nA	V _{CB} = 30V	
Concotor Cuton Current						5	μΑ	$V_{CB} = 30V, T_J = +150^{\circ}C$	
		BC846				15		V _{CE} = 80V	
Collector Emitter Cutoff Curre	ent	BC847	ICES	_	_ [15	nA	V _{CE} = 50V	
		BC848				15		V _{CE} = 30V	
Emitter Base Cutoff Current			I _{EBO}	_	_	100	nA	V _{EB} = 5V	
0	BC846A / E	3C847A / BC848A	LEGO		200				
Small Signal Current Gain (Note 10)	BC846B / E	3C847B / BC848B	h _{fe}	_	330	_	_		
(Note 10)	BC847	7C / BC848C	1		600				
Input Impedance		3C847A / BC848A	h _{ie}		2.7			1	
(Note 10)	BC846B / E	3C847B / BC848B		_	4.5	_	kΩ		
(Note 10)		BC847C / BC848C			8.7			I _C = 2.0mA, V _{CE} = 5V f=1.0kHz	
Output Admittance		BC847A / BC848A		_	18		μS		
(Note 10)	BC846B / BC847B / BC848B		h _{oe}		30	_			
(11010-10)		7C / BC848C			60				
Reverse Voltage Transfer		BC847A / BC848A		_	1.5x10 ⁻⁴				
Ratio (Note 10)	BC846B / BC847B / BC848B		h _{re}		2x10 ⁻⁴	_	_		
		7C / BC848C		110	3x10 ⁻⁴	200			
		3C847A / BC848A		110	180	220	_	I _C = 2.0mA, V _{CE} = 5V	
DC Current Gain (Note 10)		3C847B / BC848B	h _{FE}	200	290	450			
		7C / BC848C		420	520	800		1 10 1 1 0 5 1	
Collector-Emitter Saturation Voltage (Note 10)		V _{CE(sat)}	_	90	250	mV	I _C = 10mA, I _B = 0.5mA		
			02(001)		200	600		$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltage(Note 10)		V _{BE(on)}	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$		
		v BE(on)	_	_	770		$I_C = 10$ mA, $V_{CE} = 5$ V		
Base-Emitter Saturation Voltage(Note 10)		V25()	_	700		mV	$I_C = 10mA$, $I_B = 0.5mA$		
		V _{BE(sat)}		900			$I_C = 100 \text{mA}, I_B = 5 \text{mA}$		
Output Capacitance		C _{obo}	_	3	_	pF	V _{CB} = 10V, f = 1.0MHz		
Transition Frequency		f _T	100	300	_	MHz	V _{CE} = 5V, I _C = 10mA, f = 100MHz		
Noise Figure		NF	_	2	10	dB	V_{CE} =5V, I_{C} =200 μ A R_{S} =2k Ω , f=1kHz Δ f=200Hz		

Note:

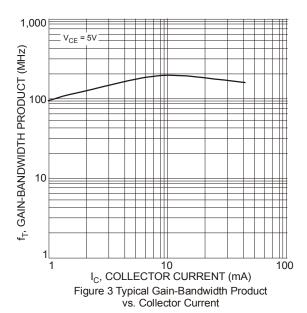
10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

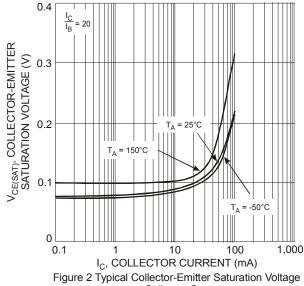


Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



 $I_{C}, \, \text{COLLECTOR} \, \, \text{CURRENT} \, \, (\text{mA})$ Figure 1 Typical DC Current Gain vs. Collector Current



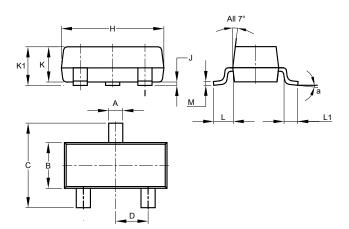


vs. Collector Current



Package Outline Dimensions

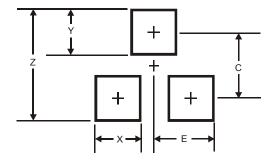
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
С	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
Н	2.80	3.00	2.90	
J	0.013	0.10	0.05	
K	0.890	1.00	0.975	
K1	0.903	1.10	1.025	
L	0.45	0.61	0.55	
L1	0.25	0.55	0.40	
М	0.085	0.150	0.110	
а	8°			
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
E	1.35		



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